NSN 5961-01-462-9728

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-462-9728 **Inclosure Material:** Glass **End Application:** 6625-01-425-2551 **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 25.0 base supply voltage and 30.0 reverse voltage, instantaneous **Capacitance Rating In Picofarads:** Between 2.0 and 12.6 **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction Shelf Life: N/a **Unit Of Measure:** Demilitarization: No

Fiig: A110a0